








	<p>SI3440DV-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI3440DV-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 150V 1.2A 6-TSOP</p> <p>Datenblätter:  SI3440DV-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 56930 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI3440DV-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 150V 1.2A 6-TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	56930 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	1.14W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	150V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1.2A (Ta)
Rds On (Max) @ Id, Vgs	375 mOhm @ 1.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	8nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Antriebsspannung (Max Rds On, Min Rds On)	6V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































SI3440DV-T1-GE3 ist neu im Original, Suche SI3440DV-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3440DV-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3440DV-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI3440ADV-T1-GE3 VISHAY VISHAY TSOP-6</p>	 <p>SI3440DV-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 150V 1.2A 6-TSOP</p>	 <p>SI3441BDV-T1-E3 Vishay / Siliconix MOSFET P-CH 20V 2.45A 6-TSOP</p>	 <p>SI3441BDV VISHAY SI3441BDV VISHAY</p>
 <p>SI3438DV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 40V 7.4A 6-TSOP</p>	 <p>SI3440ADV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 150V 2.2A 6TSOP</p>	 <p>SI3440DV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 150V 1.2A 6-TSOP</p>	 <p>SI3441BDV-T1 VISHAY SI3441BDV-T1 VISHAY</p>

heiße Teile

Mehr

 SI3433DV-T1	 SI3433DV-T1-E	 SI3433DV-T1-E3	 SI3433DV-T1-GE3	 SI3434DV-T1
 SI3434DV-T1-E3	 SI3434DV-T1-E3	 SI3434DV-T1-GE3	 SI3434DV-T1-GE3	 SI3435DV-T1
 SI3435DV-T1-E3	 SI3435DV-T1-GE3	 SI3437DV-T1-E3	 SI3437DV-T1-E3	 SI3437DV-T1-GE3
 SI3437DV-T1-GE3	 SI3438DV-T1-E3	 SI3438DV-T1-E3	 SI3438DV-T1-GE3	 SI3438DV-T1-GE3
 SI3440ADV-T1-GE3	 SI3440ADV-T1-GE3	 SI3440DV-T1-E3	 SI3440DV-T1-E3	 SI3440DV-T1-GE3
 SI3441BDV	 SI3441BDV-T1	 SI3441BDV-T1-E3	 SI3441BDV-T1-E3	 SI3441BDV-T1-GE3
 SI3441BDV-T1-GE3	 SI3441DV	 SI3441DV-NL	 SI3441DV-T1	 SI3441DV-T1-E3
 SI3441DV-T2	 SI3441DV-T1-E3	 SI3442BDV	 SI3442BDV-T1-E3	 SI3442BDV-T1-E3
 SI3442BDV-T1-GE3	 SI3442BDV-T1-GE3	 SI3442CDV-T1-GE3	 SI3442CDV-T1-GE3	 SI3442DV
 SI3442DV	 SI3442DV-T1	 SI3442DV-T1-E3	 SI3442DV-T1-GE3	 SI3443ADV-T1-E3

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